

# Central<sup>TM</sup> Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

www.centrasemi.com

MCR22-6  
MCR22-8SENSITIVE GATE  
SILICON CONTROLLED RECTIFIER

TO-92 CASE

**DESCRIPTION**

The CENTRAL SEMICONDUCTOR MCR22 series types are PNP Sensitive Gate Silicon Controlled Rectifiers manufactured in a TO-92 case, designed for CD ignition, fuel igniters, flash circuits, and motor control applications.

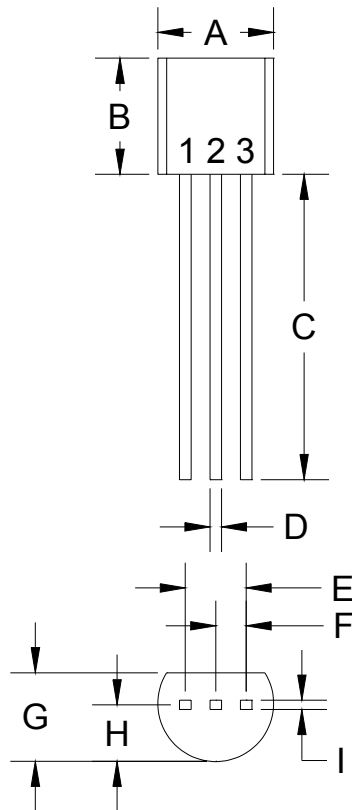
**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

|                                                       | <u>SYMBOL</u>      | <u>MRC22-6</u> | <u>MRC22-8</u> | <u>UNITS</u>         |
|-------------------------------------------------------|--------------------|----------------|----------------|----------------------|
| Peak Repetitive Off-State Voltage                     | $V_{DRM}, V_{RRM}$ | 400            | 600            | V                    |
| RMS On-State Current ( $T_C = 80^\circ\text{C}$ )     | $I_T(\text{RMS})$  | 1.5            |                | A                    |
| Non Rept. On-State Current                            | $I_{TSM}$          | 15             |                | A                    |
| Fusing Current ( $t=8.3\text{ms}$ )                   | $I_t$              | 0.9            |                | $\text{A}^2\text{s}$ |
| Peak Reverse Gate Voltage ( $t \leq 1.0\mu\text{s}$ ) | $V_{GRM}$          | 5.0            |                | V                    |
| Forward Peak Gate Current ( $t \leq 1.0\mu\text{s}$ ) | $I_{FGM}$          | 0.2            |                | A                    |
| Peak Gate Dissipation ( $t \leq 1.0\mu\text{s}$ )     | $P_{GM}$           | 0.5            |                | W                    |
| Gate Dissipation ( $t=8.3\text{ms}$ )                 | $P_G(\text{AV})$   | 0.1            |                | W                    |
| Operating Junction Temperature                        | $T_J$              | -40 to +125    |                | $^\circ\text{C}$     |
| Storage Temperature                                   | $T_{stg}$          | -40 to +150    |                | $^\circ\text{C}$     |
| Thermal Resistance                                    | $\Theta_{JC}$      | 50             |                | $^\circ\text{C/W}$   |
| Thermal Resistance                                    | $\Theta_{JA}$      | 160            |                | $^\circ\text{C/W}$   |

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| <u>SYMBOL</u>      | <u>TEST CONDITIONS</u>                                                            | <u>MIN</u> | <u>TYP</u> | <u>MAX</u> | <u>UNITS</u>     |
|--------------------|-----------------------------------------------------------------------------------|------------|------------|------------|------------------|
| $I_{DRM}, I_{RRM}$ | Rated $V_{DRM}, V_{RRM}$ , $R_{GK}=1.0\text{k}\Omega$ , $T_C = 25^\circ\text{C}$  |            |            | 10         | $\mu\text{A}$    |
| $I_{DRM}, I_{RRM}$ | Rated $V_{DRM}, V_{RRM}$ , $R_{GK}=1.0\text{k}\Omega$ , $T_C = 125^\circ\text{C}$ |            |            | 200        | $\mu\text{A}$    |
| $V_{TM}$           | $I_T=1.0\text{A}$                                                                 |            |            | 1.7        | V                |
| $I_{GT}$           | $V_{AK}=6.0\text{V}$ , $R_L=100\Omega$ , $T_C = 25^\circ\text{C}$                 |            |            | 200        | $\mu\text{A}$    |
| $I_{GT}$           | $V_{AK}=6.0\text{V}$ , $R_L=100\Omega$ , $T_C = -40^\circ\text{C}$                |            |            | 500        | $\mu\text{A}$    |
| $V_{GT}$           | $V_{AK}=7.0\text{V}$ , $R_L=100\Omega$ , $T_C = 25^\circ\text{C}$                 |            |            | 0.8        | V                |
| $V_{GT}$           | $V_{AK}=7.0\text{V}$ , $R_L=100\Omega$ , $T_C = -40^\circ\text{C}$                |            |            | 1.2        | V                |
| $V_{GD}$           | $V_{AK}=12\text{V}$ , $R_L=100\Omega$ , $T_C = 110^\circ\text{C}$                 | 0.1        |            |            | V                |
| $I_H$              | $V_{AK}=12\text{V}$ , $I_{AK}=200\text{mA}$ , $T_C = 25^\circ\text{C}$            |            |            | 5.0        | mA               |
| $I_H$              | $V_{AK}=12\text{V}$ , $I_{AK}=200\text{mA}$ , $T_C = -40^\circ\text{C}$           |            |            | 10         | mA               |
| dv/dt              | $T_C = 110^\circ\text{C}$                                                         |            | 25         |            | V/ $\mu\text{s}$ |

(SEE REVERSE SIDE)

TO-92 PACKAGE - MECHANICAL OUTLINE

| DIMENSIONS |        |       |             |      |
|------------|--------|-------|-------------|------|
| SYMBOL     | INCHES |       | MILLIMETERS |      |
|            | MIN    | MAX   | MIN         | MAX  |
| A (DIA)    | 0.175  | 0.205 | 4.45        | 5.21 |
| B          | 0.170  | 0.210 | 4.32        | 5.33 |
| C          | 0.500  | -     | 12.70       | -    |
| D          | 0.016  | 0.022 | 0.41        | 0.56 |
| E          | 0.100  |       | 2.54        |      |
| F          | 0.050  |       | 1.27        |      |
| G          | 0.125  | 0.165 | 3.18        | 4.19 |
| H          | 0.080  | 0.105 | 2.03        | 2.67 |
| I          | 0.015  |       | 0.38        |      |

TO-92 (REV: R1)

Lead Code: 1) Cathode  
2) Gate  
3) Anode

R1

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## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

#### Corporate Headquarters & Customer Support Team

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